



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings Ta=25°C unless otherwise noted

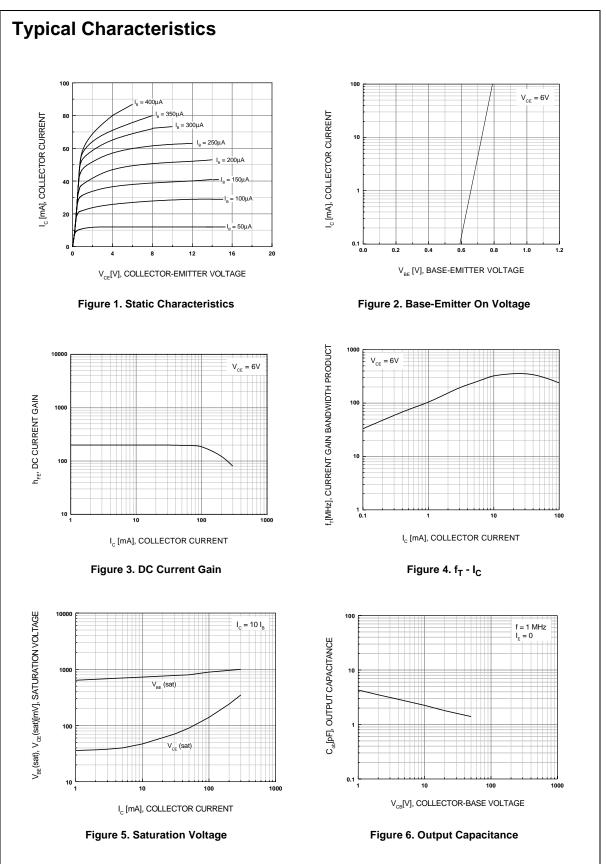
| Symbol | Parameter | Value | Units |
|------------------|-----------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 60 | V |
| V _{CEO} | Collector-Emitter Voltage | 50 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 150 | mA |
| Pc | Collector Power Dissipation | 250 | mW |
| ТJ | Junction Temperature | 150 | °C |
| Т _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics Ta=25°C unless otherwise noted

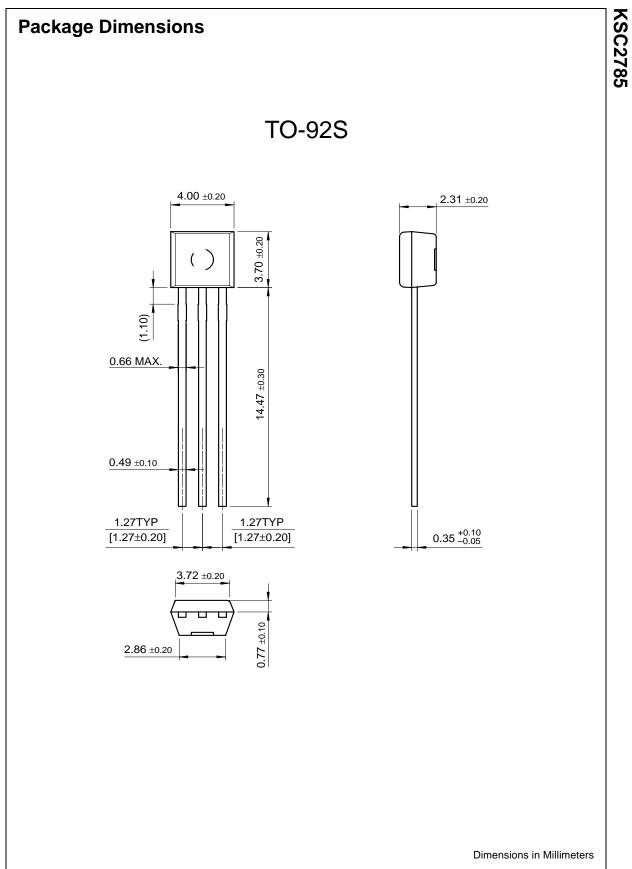
| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|---|------|------|------|-------|
| BV _{CBO} | Collector-Base Breakdown Voltage | I _C =100μΑ, I _E =0 | 60 | | | V |
| BV _{CEO} | Collector-Emitter Breakdown Voltage | tor-Emitter Breakdown Voltage I _C =10mA, I _B =0 | | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | I _E =10μA, I _C =0 | 5 | | | V |
| I _{CBO} | Collector Cut-off Current | V _{CB} =40V, I _E =0 | | | 0.1 | μA |
| IEBO | Emitter Cut-off Current | V _{EB} =3V, I _C =0 | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V _{CE} =6V, I _C =1.0mA | 70 | | 700 | - 15 |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =100mA, I _B =10mA | | 0.15 | 0.3 | V |
| f _T | Current Gain Bandwidth Product | V _{CE} =6V, I _C =10mA | | 300 | LIL. | MHz |
| C _{ob} | Output Capacitance | V _{CB} =6V, I _E =0, f=1MHz | | 2.5 | . OZ | pF |
| NF | Noise Figure | V _{CE} =6, I _C =0.5mA f=1KHz, R _S =500Ω | | 4.0 | | dB |

| Classification | 0 | Y | G | L |
|-----------------|----------|-----------|-----------|-----------|
| h _{FE} | 70 ~ 140 | 120 ~ 240 | 200 ~ 400 | 350 ~ 700 |





KSC2785



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|--------------------------|---------------------------|---|
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